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Scalable integrated single-photon source

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Photonic qubits are key enablers for quantum information processing deployable across a distributed quantum network. An on-demand and truly scalable source of indistinguishable single photons is the essential component enabling high-fidelity photonic quantum operations. A main challenge is to overcome noise and decoherence processes to reach the steep benchmarks on generation efficiency and photon indistinguishability required for scaling up the source. We report on the realization of a deterministic single-photon source featuring near-unity indistinguishability using a quantum dot in an “on-chip” planar nanophotonic waveguide circuit. The device produces long strings of >100 single photons without any observable decrease in the mutual indistinguishability between photons. A total generation rate of 122 million photons per second is achieved, corresponding to an on-chip source efficiency of 84%. These specifications of the single-photon source are benchmarked for boson sampling and found to enable scaling into the regime of quantum advantage.

INTRODUCTION

Leveraging photonic quantum technology requires scalable hardware. A key enabling device is a high-quality and on-demand source of indistinguishable single photons with immediate use for quantum simulators (1), device-independent quantum communication (2), and memoryless quantum Repeaters (3), or as a primer for multiphoton entanglement sources (4). Furthermore, single photons are the natural carriers of quantum information over extended distances, thereby providing a backbone for the quantum internet (5) by enabling fully secure quantum communication (6) and a modular approach to quantum computing (7, 8).

An on-demand source of indistinguishable single photons is the major building block that can be realized either with a probabilistic source, which can be heralded and multiplexed to improve efficiency (9), or using a single quantum emitter coupled to a waveguide or cavity designed to collect the spontaneously emitted single photons. Substantial progress has been made with the latter approach by coupling quantum dots (QDs) to photonic nanostructures (10–20), and the governing fundamental processes determining performance have now clearly been identified including decoherence processes (21). Nonetheless, deterministic operation of a source of high-quality indistinguishable photons on a scalable platform has not yet been achieved, which is a key enabling step toward demonstrating quantum advantage with single photons (22, 23). Quantum advantage has so far been reported with superconducting qubits (24), while the state of the art in photonics is the 20-photon experiment reported with a QD source (25). Deterministic and coherent operation of a photon source requires a number of simultaneous capabilities: (i) The QD must be deterministically and resonantly excited with a tailored optical pulse while eliminating the excess pump light without reducing the single-photon purity and efficiency, (ii) the emitted photon must be efficiently coupled to a single propagating mode, (iii) electrical control of the QD must be implemented to overcome efficiency loss due to emission into other QD charge states, and (iv) decoherence and noise processes must be eliminated over the relevant time scale (26) to produce a scalable source of multiple indistinguishable photons.

In the present work, we implement all four functionalities in a single device, using a QD efficiently coupled to an electrically contacted planar photonic crystal waveguide membrane. We generate temporal strings of >100 single photons with pairwise photon indistinguishability exceeding 96%. Such a source coupled with an active temporal-to-spatial mode demultiplexer (14, 27) will realize a paradigm shift for multiphoton experiments aimed at establishing photonic quantum advantage that requires more than 50 photons (22, 28). In a recent breakthrough experiment, up to 20 photons were used in a boson sampling experiment (25); however, the photon indistinguishability was observed to decay over the 20-photon chain. This loss of coherence was also reported in previous experiments and only explained heuristically (29), and is likely a consequence of insufficient control of the QD charge environment leading to noise. Conceptually, the charge noise induces blinking of the QD that results in a loss of efficiency along with the broadening of the emission spectrum, which implies reduced coherence of the single-photon train. We implement electrical control of QDs coupled to photonic crystal waveguides through precise nanofabrication of low-noise electrical contacts that suppresses these detrimental effects. Our approach of combining high-quality semiconductor heterostructure growth together with advanced device design and nanofabrication is shown to robustly recover the transform-limited emission line shape (30), which is a key indicator for the generation of highly coherent single photons. In our improved source, we demonstrate coherence extending to at least 115 photons, as is proven by measuring the mutual degree of indistinguishability between photons emitted with a time delay approaching a microsecond. The source efficiency specifying the “on-chip” generation probability of indistinguishable single photons is $\eta = 84\%$, which is composed of 92% coupling of the dipole to the waveguide (the $\beta$ factor), 95% efficient emission into the coherent zero-photon line, 98% radiative decay efficiency, and >98% emission of the best-coupled of the two linear dipoles. Overall, we demonstrate the generation of 122 million photons per second in the waveguide, which is the main efficiency figure of merit that the present experiment targets. This massive photonic quantum resource is coupled off-chip and into an optical fiber, with an efficiency limited only by minor residual loss (4%) in

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the waveguide and a chip-to-fiber outcoupling efficiency that reaches up to 82% with optimized grating outcouplers. The full details of the efficiency characterizations are presented in the Supplementary Materials in addition to an account of how to optimize external coupling efficiencies with already demonstrated methods to reach a fiber-coupled source with an overall efficiency of 78%. The improved source coherence will result in shorter runtimes for the validation of boson sampling in the quantum regime, thereby overcoming a major technological challenge. Our work lays a clear pathway for demonstrating quantum advantage in boson sampling with >50 photons using the source in combination with realistic low-loss optical networks and high-efficiency detectors.

**RESULTS**

**Operational principle of the single-photon device**

Figure 1 displays the device comprising epitaxially grown QDs embedded in a 180-nm-thin membrane (see section S1 for details on sample fabrication). The QD is excited with short optical pulses whereby an excitation in the QD can be deterministically prepared. The emitted single photons are channeled on-demand into a photonic crystal waveguide designed to control the local density of optical states such that an embedded QD emits with near-unity coupling efficiency (quantified by the β factor) into the waveguide (10). The collected photons are subsequently routed on-chip and directed to a tailored grating for highly efficient outcoupling to an optical fiber. The spatial separation between the excitation laser and the collection grating ensures that very high suppression of the pulsed resonant laser can be obtained without using any polarization filtering that could result in losses. Figure 2B shows an example of pulsed resonance fluorescence data that exhibit clear Rabi oscillation with highly suppressed laser background.

**Demonstration of low-noise operation**

The implementation of electrical contacts on the device (cf. Fig. 1) leads to a number of salient features: The embedded QDs can be electrically tuned, the charge state of the QD is stabilized so that emission only on the desired transition takes place, and spectral diffusion due to residual charge noise in the structures can be strongly suppressed. As a consequence, near–transform-limited optical line-widths can be achieved in the photonic nanostructures (19, 30, 31), which is essential for generating a scalable resource of indistinguishable photons as well as for more advanced applications of the system for photonic quantum gates and entanglement generation (21). Low-noise operation is demonstrated by exciting the QD with a tunable laser and collecting the resonance fluorescence. A typical measurement is displayed in Fig. 2A, where two distinct QD transitions (the two orthogonal dipoles of the neutral exciton) are visible and the excitation laser is clearly suppressed. A distinct Coulomb blockade regime is observed (32), meaning that the QD emits solely on the identified neutral exciton transition; i.e., blinking to other exciton complexes is fully suppressed. We observe a QD linewidth of ∼800 MHz, which is close to the transform limit, and the slight residual broadening is attributed to the slow time drift (1 to 10 ms) (33), which is irrelevant for the generation of indistinguishable photons over the nanosecond to microsecond time scales studied here.

**Deterministic single-photon generation**

Pulsed resonant excitation allows on-demand operation of the single-photon device. The QD was excited with 20-ps pulses, and clear Rabi oscillations are observed when increasing the excitation power (cf. Fig. 2B). The measured 10.4-MHz peak single-photon detection rate for a 145-MHz pump laser repetition rate is in good agreement with the estimated source efficiency (ηs = 84%; cf. table S1) for the nonoptimum setup efficiency of ≈8.4%, resulting in an in-fiber efficiency of 7%. We note that the setup efficiency can be readily optimized (see section S5.4) using off-the-shelf equipment and proven device designs to exceed 82%. Deterministic operation corresponds to excitation with a π pulse, where essentially background-free operation is observed with a very low single-photon impurity contribution of ξ < 0.007. Here, ξ is defined as the ratio of the laser background to the QD signal intensity. The single-photon purity is quantified in second-order photon correlation measurements (cf. data in Fig. 2D). We extract χ(2)(0) = 0.015 ± 0.005, which can be further improved by engineering the resonant excitation pulse (34) or by implementing two-photon excitation schemes (35). Blinking of the source is essentially vanishing (cf. inset of Fig. 2D) up to time scales approaching milliseconds (data up to 50 μs shown). The photon emission dynamics is reproduced in Fig. 2C, where a radiative decay rate of γ = 2.89 ns⁻¹ is extracted for the efficiently coupled dipole, which is enhanced by the Purcell effect of the waveguide leading to the large β factor (11).

**Generation of long strings of indistinguishable photons**

The indistinguishability of the temporal single-photon train is quantified through photon-photon interference experiments. In these measurements, two photons emitted at different times are interfered in an asymmetric interferometer with a variable time delay, as schematized in Fig. 3A. In this setup, we can measure the degree of indistinguishability between single photons emitted from the QD with time intervals Nτp, where τp is the laser repetition period and N is a positive integer. Figure 3C shows experimental data for the four representative values N = [1, 38, 76, 114], where the latter corresponds to a maximum time delay between two photons of 786.6 ns. Figure 3B shows the recorded correlation histograms for N = 1 and N = 114 for the two cases where the interfering photons are co- and cross-polarized. The cross-polarized histogram serves as a reference measurement for extracting the degree of indistinguishability V after accounting for the setup imperfections (cf. section S4 for the analysis).

![Fig. 1 Illustation of the single-photon source device.](image-url)
We find $V = (96 \pm 2\%)$ when accounting for the finite multiphoton probability discussed above, while $V = (93 \pm 2\%)$ is directly recorded. The minor amount of distinguishability can be attributed to the residual elastic phonon scattering (36), which is the fundamental decoherence process that determines the performance of QD single-photon sources. The degree of indistinguishability due to phonon scattering is dependent on the photonic nanostructure owing to the quantized phonon modes (37) and the sample temperature. At the sample temperature of 1.6 K, in our measurements, the expected indistinguishability is $\approx 98\%$ in the photonic crystal membrane, where the experimental values are limited by the finite resolution of the interferometer. We find the photon indistinguishability to remain over 96% for delays corresponding to 115 photons (cf. Fig. 3C), which is key for the applicability of the source to reach quantum advantage, as benchmarked below.

**DISCUSSION**

Scalable boson sampling experiments using QD sources use active switching of the temporal string of single photons into separate...
against the classically simulatable case of distinguishable photons requires a QD source efficiency, logistically feasible operation time of 30 days. We find that reaching for boson sampling versus the number of photons for a technologically feasible time (cf. fig. S1A for the heterostructure design). The first step in creating the nanostructures is the fabrication of the electrical contacts to the p-doped and n-doped layers. Reactive-ion etching in a BCl3/Ar plasma is used to open vias to the n layer, and Ni/Ge/Au/Ni/Au contacts are deposited by electron beam physical vapor deposition and annealed at 430°C. Subsequently, Cr/Au pads are deposited on the surface to realize ohmic p-type contacts. The nanostructuring is then carried out using a soft mask–based process described in (42). The residual polymer from the soft mask is removed by dipping the sample in N-methyl-pyrrolidone at 70°C. The sacrificial layer is then removed using wet etching using hydrofluoric acid to release the membrane.

Experimental setup

The sample is cooled to 1.6 K in a cryostat with optical and electrical access. The QD is excited from the top of the chip using a wide-field-of-view confocal microscope with a high numerical aperture objective (NA = 0.81) (cf. fig. S4A). The emission from the QD is collected at the grating outcoupler through the same objective and imaged onto a single-mode optical fiber. The excitation and collection paths are separated at a 5:95 (reflection/transmission) beam splitter, with the 95% transmission path for collection. A set of quarter- and half-wave plates in the excitation path allow polarization control of the excitation laser. The QD emission collected in the fiber is spectrally filtered using a 3-GHz linewidth etalon (free spectral range: 100 GHz) to suppress the emission in the phonon sideband. The intensity of the spectrally filtered emission is measured using a fiber–coupled superconducting nanowire single-photon detector. The bias voltage across the QD is tuned using a low-noise high-resolution DC voltage source.

REFERENCES AND NOTES


MATERIALS AND METHODS

Sample fabrication

The samples are fabricated on a gallium arsenide (GaAs) membrane grown by molecular beam epitaxy on a (100) GaAs substrate. The substrate is prepared for growth using an aluminum arsenide (AlAs)/GaAs superlattice followed by the growth of a 1150-nm-thick Al0.75Ga0.25As sacrificial layer. Subsequently, a 180-nm-thin GaAs membrane containing indium arsenide (InAs) QDs is grown on top of the sacrificial layer. The membrane constitutes an ultrathin p-i-n diode (cf. fig. S1A for the heterostructure design). The first step in creating the nanostructures is the fabrication of the electrical contacts to the p-doped and n-doped layers. Reactive-ion etching in a BCl3/Ar plasma is used to open vias to the n layer, and Ni/Ge/Au/Ni/Au contacts are deposited by electron beam physical vapor deposition and annealed at 430°C. Subsequently, Cr/Au pads are deposited on the surface to realize ohmic p-type contacts. The nanostructuring is then carried out using a soft mask–based process described in (42). The residual polymer from the soft mask is removed by dipping the sample in N-methyl-pyrrolidone at 70°C. The sacrificial layer is then removed using wet etching using hydrofluoric acid to release the membrane.


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